

AMC1400-Q1 Automotive, Precision, ± 250 -mV Input, Reinforced Isolated Amplifier in a 15-mm Stretched SOIC Package

1 Features

- AEC-Q100 qualified for automotive applications:
 - Temperature grade 1: -40°C to $+125^{\circ}\text{C}$, T_A
- Functional Safety-Capable
 - Documentation available to aid functional safety system design
- ± 250 -mV input voltage range optimized for current measurements using shunt resistors
- Fixed gain: 8.2 V/V
- Low DC errors:
 - Offset error: ± 0.2 mV (max)
 - Offset drift: ± 0.9 $\mu\text{V}/^{\circ}\text{C}$ (max)
 - Gain error: $\pm 0.3\%$ (max)
 - Gain drift: ± 30 ppm/ $^{\circ}\text{C}$ (max)
 - Nonlinearity: 0.03% (max)
- 3.3-V or 5-V operation on high-side and low-side
- Missing high-side supply detection feature
- High CMTI: 100 kV/ μs (min)
- Low EMI, meets CISPR-11 and CISPR-25 standards
- Safety-related certifications:
 - 10600- V_{PK} reinforced isolation per DIN EN IEC 60747-17 (VDE 0884-17)
 - 7500- V_{RMS} isolation for 1 minute per UL1577

2 Applications

- Shunt-resistor-based current sensing in:
 - HEV/EV charging piles
 - HEV/EV on-board chargers (OBC)
 - HEV/EV DC/DC converters
 - HEV/EV traction inverters

3 Description

The AMC1400-Q1 is a precision, isolated amplifier with an output separated from the input circuitry by an isolation barrier that is highly resistant to magnetic interference. This barrier is certified to provide reinforced galvanic isolation of up to 7.5 kV_{RMS} according to DIN EN IEC 60747-17 (VDE 0884-17) and UL1577, and supports a working voltage of up to 2 kV_{RMS}.

The isolation barrier separates parts of the system that operate on different common-mode voltage levels and protects the low-side from voltage levels that can cause electrical damage and are potentially harmful to an operator.

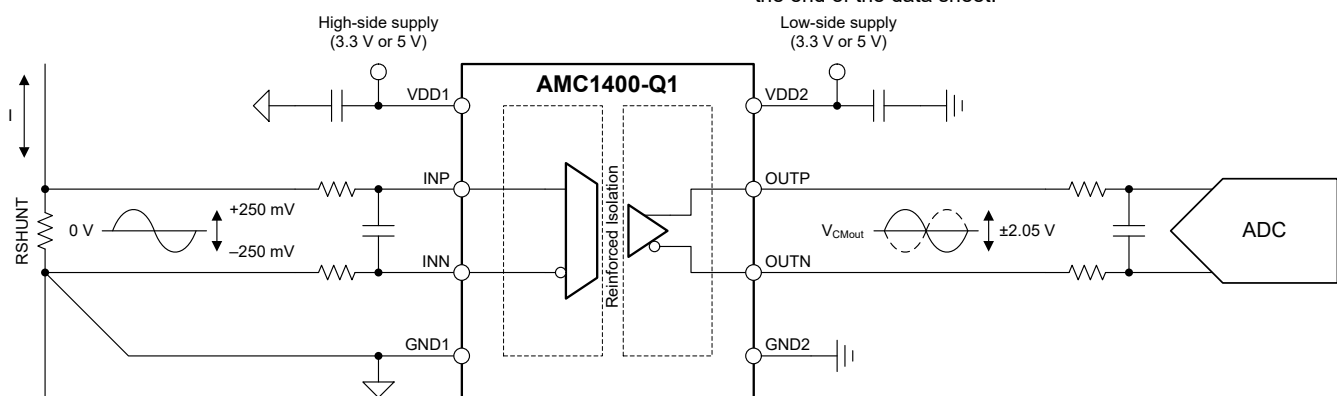
The input of the AMC1400-Q1 is optimized for direct connection to a low-impedance shunt resistor or other low-impedance voltage source with low signal levels. The excellent DC accuracy and low temperature drift supports accurate current control in power factor correction (PFC) stages, DC/DC converters, traction inverters, and other applications that must operate at high common-mode voltages, high altitudes, or in environments with high pollution degrees.

The AMC1400-Q1 is offered in a stretched 8-pin SOIC package and is AEC-Q100 qualified for automotive applications and supports the temperature range from -40°C to $+125^{\circ}\text{C}$.

Package Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|----------|--------------------|
| AMC1400-Q1 | SOIC (8) | 6.40 mm × 14.00 mm |

- (1) For all available packages, see the orderable addendum at the end of the data sheet.



Typical Application



Table of Contents

| | | | |
|--|-----------|--|-----------|
| 1 Features | 1 | 7.1 Overview..... | 17 |
| 2 Applications | 1 | 7.2 Functional Block Diagram..... | 17 |
| 3 Description | 1 | 7.3 Feature Description..... | 17 |
| 4 Revision History | 2 | 7.4 Device Functional Modes..... | 19 |
| 5 Pin Configuration and Functions | 3 | 8 Application and Implementation | 20 |
| 6 Specifications | 4 | 8.1 Application Information..... | 20 |
| 6.1 Absolute Maximum Ratings..... | 4 | 8.2 Typical Application..... | 20 |
| 6.2 ESD Ratings..... | 4 | 8.3 Best Design Practices..... | 25 |
| 6.3 Recommended Operating Conditions..... | 4 | 8.4 Power Supply Recommendations..... | 26 |
| 6.4 Thermal Information..... | 5 | 8.5 Layout..... | 27 |
| 6.5 Power Ratings..... | 5 | 9 Device and Documentation Support | 28 |
| 6.6 Insulation Specifications..... | 6 | 9.1 Documentation Support..... | 28 |
| 6.7 Safety-Related Certifications..... | 7 | 9.2 Receiving Notification of Documentation Updates..... | 28 |
| 6.8 Safety Limiting Values..... | 7 | 9.3 Support Resources..... | 28 |
| 6.9 Electrical Characteristics..... | 8 | 9.4 Trademarks..... | 28 |
| 6.10 Switching Characteristics..... | 9 | 9.5 Electrostatic Discharge Caution..... | 28 |
| 6.11 Timing Diagram..... | 9 | 9.6 Glossary..... | 28 |
| 6.12 Insulation Characteristics Curves..... | 10 | 10 Mechanical, Packaging, and Orderable Information | 28 |
| 6.13 Typical Characteristics..... | 11 | | |
| 7 Detailed Description | 17 | | |

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| DATE | REVISION | NOTES |
|-----------|----------|-----------------|
| July 2022 | * | Initial Release |

5 Pin Configuration and Functions



Figure 5-1. DWL Package, 8-Pin SOIC (Top View)

Table 5-1. Pin Functions

| PIN | | TYPE | DESCRIPTION |
|-----|------|------------------|--|
| NO. | NAME | | |
| 1 | VDD1 | High-side power | High-side power supply. ⁽¹⁾ |
| 2 | INP | Analog input | Noninverting analog input. Either INP or INN must have a DC current path to GND1 to define the common-mode input voltage. ⁽²⁾ |
| 3 | INN | Analog input | Inverting analog input. Either INP or INN must have a DC current path to GND1 to define the common-mode input voltage. ⁽²⁾ |
| 4 | GND1 | High-side ground | High-side analog ground. |
| 5 | GND2 | Low-side ground | Low-side analog ground. |
| 6 | OUTN | Analog output | Inverting analog output. |
| 7 | OUTP | Analog output | Noninverting analog output. |
| 8 | VDD2 | Low-side power | Low-side power supply. ⁽¹⁾ |

(1) See the [Power Supply Recommendations](#) section for power-supply decoupling recommendations.

(2) See the [Layout](#) section for details.

6 Specifications

6.1 Absolute Maximum Ratings

see⁽¹⁾

| | | MIN | MAX | UNIT |
|----------------------|--|------------|------------|------|
| Power-supply voltage | High-side VDD1 to GND1 | −0.3 | 6.5 | V |
| | Low-side VDD2 to GND2 | −0.3 | 6.5 | |
| Analog input voltage | INP, INN | GND1 − 6 | VDD1 + 0.5 | V |
| Output voltage | OUTP, OUTN | GND2 − 0.5 | VDD2 + 0.5 | V |
| Input current | Continuous, any pin except power-supply pins | −10 | 10 | mA |
| Temperature | Junction, T _J | | 150 | °C |
| | Storage, T _{stg} | −65 | 150 | |

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| V _(ESD) | Electrostatic discharge | Human-body model (HBM), per AEC Q100-002 ⁽¹⁾ , HBM ESD classification Level 2 | ±2000 | V |
| | | Charged-device model (CDM), per AEC Q100-011, CDM ESD classification Level C6 | ±1000 | |

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

| | | | MIN | NOM | MAX | UNIT |
|--------------------------|---|---|-------|------|------------|------|
| POWER SUPPLY | | | | | | |
| | High-side power supply | VDD1 to GND1 | 3 | 5 | 5.5 | V |
| | Low-side power supply | VDD2 to GND2 | 3 | 3.3 | 5.5 | V |
| ANALOG INPUT | | | | | | |
| V _{Clipping} | Differential input voltage before clipping output | V _{IN} = V _{INP} − V _{INN} | | ±320 | | mV |
| V _{FSR} | Specified linear differential full-scale voltage | V _{IN} = V _{INP} − V _{INN} | −250 | | 250 | mV |
| V _{CM} | Operating common-mode input voltage | (V _{INP} + V _{INN}) / 2 to GND1 | −0.16 | | VDD1 − 2.1 | V |
| ANALOG OUTPUT | | | | | | |
| C _{LOAD} | Capacitive load | On OUTP or OUTN to GND2 | | | 500 | pF |
| C _{LOAD} | Capacitive load | OUTP to OUTN | | | 250 | pF |
| R _{LOAD} | Resistive load | On OUTP or OUTN to GND2 | | 10 | 1 | kΩ |
| TEMPERATURE RANGE | | | | | | |
| T _A | Specified ambient temperature | | −40 | 25 | 125 | °C |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | DWL (SOIC) | UNIT |
|-------------------------------|--|------------|------|
| | | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 63.2 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 26.1 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 28.5 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 7.8 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 26.8 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Power Ratings

| PARAMETER | | TEST CONDITIONS | VALUE | UNIT |
|-----------|--|---------------------|-------|------|
| P_D | Maximum power dissipation (both sides) | VDD1 = VDD2 = 5.5 V | 99 | mW |
| P_{D1} | Maximum power dissipation (high-side) | VDD1 = 3.6 V | 31 | mW |
| | | VDD1 = 5.5 V | 54 | |
| P_{D2} | Maximum power dissipation (low-side) | VDD2 = 3.6 V | 26 | mW |
| | | VDD2 = 5.5 V | 45 | |

6.6 Insulation Specifications

over operating ambient temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | VALUE | UNIT |
|--|---|--|--------------------|------------------|
| GENERAL | | | | |
| CLR | External clearance ⁽¹⁾ | Shortest pin-to-pin distance through air | ≥ 14.7 | mm |
| CPG | External creepage ⁽¹⁾ | Shortest pin-to-pin distance across the package surface | ≥ 15.7 | mm |
| DTI | Distance through insulation | Minimum internal gap (internal clearance) of the double insulation | ≥ 21 | μm |
| CTI | Comparative tracking index | DIN EN 60112 (VDE 0303-11); IEC 60112 | ≥ 600 | V |
| | Material group | According to IEC 60664-1 | I | |
| | Overvoltage category per IEC 60664-1 | Rated mains voltage ≤ 600 V _{RMS} | I-IV | |
| | | Rated mains voltage ≤ 1000 V _{RMS} | I-III | |
| DIN EN IEC 60747-17 (VDE 0884-17) ⁽²⁾ | | | | |
| V _{IORM} | Maximum repetitive peak isolation voltage | At AC voltage | 2800 | V _{PK} |
| V _{IOWM} | Maximum-rated isolation working voltage | At AC voltage (sine wave) | 2000 | V _{RMS} |
| | | At DC voltage | 2800 | V _{DC} |
| V _{IOTM} | Maximum transient isolation voltage | V _{TEST} = V _{IOTM} , t = 60 s (qualification test) | 10600 | V _{PK} |
| | | V _{TEST} = 1.2 × V _{IOTM} , t = 1 s (100% production test) | 12720 | |
| V _{IMP} | Maximum impulse voltage ⁽³⁾ | Tested in air, 1.2/50-μs waveform per IEC 62368-1 | 9800 | V _{PK} |
| V _{IOSM} | Maximum surge isolation voltage ⁽⁴⁾ | Tested in oil (qualification test), 1.2/50-μs waveform per IEC 62368-1 | 12800 | V _{PK} |
| q _{pd} | Apparent charge ⁽⁵⁾ | Method a, after input/output safety test subgroups 2 and 3, V _{ini} = V _{IOTM} , t _{ini} = 60 s, V _{pd(m)} = 1.2 × V _{IORM} , t _m = 10 s | ≤ 5 | pC |
| | | Method a, after environmental tests subgroup 1, V _{ini} = V _{IOTM} , t _{ini} = 60 s, V _{pd(m)} = 1.6 × V _{IORM} , t _m = 10 s | ≤ 5 | |
| | | Method b1, at routine test (100% production) and preconditioning (type test), V _{ini} = V _{IOTM} , t _{ini} = 1 s, V _{pd(m)} = 1.875 × V _{IORM} , t _m = 1 s | ≤ 5 | |
| C _{IO} | Barrier capacitance, input to output ⁽⁶⁾ | V _{IO} = 0.5 V _{PP} at 1 MHz | ~1.5 | pF |
| R _{IO} | Insulation resistance, input to output ⁽⁶⁾ | V _{IO} = 500 V at T _A = 25°C | > 10 ¹² | Ω |
| | | V _{IO} = 500 V at 100°C ≤ T _A ≤ 125°C | > 10 ¹¹ | |
| | | V _{IO} = 500 V at T _S = 150°C | > 10 ⁹ | |
| | Pollution degree | | 2 | |
| | Climatic category | | 55/125/21 | |
| UL1577 | | | | |
| V _{ISO} | Withstand isolation voltage | V _{TEST} = V _{ISO} = 7500 V _{RMS} , t = 60 s (qualification), V _{TEST} = 1.2 × V _{ISO} = 9000 V _{RMS} , t = 1 s (100% production test) | 7500 | V _{RMS} |

- (1) Apply creepage and clearance requirements according to the specific equipment isolation standards of an application. Care must be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed circuit board (PCB) do not reduce this distance. Creepage and clearance on a PCB become equal in certain cases. Techniques such as inserting grooves, ribs, or both on a PCB are used to help increase these specifications.
- (2) This coupler is suitable for *safe electrical insulation* only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.
- (3) Testing is carried out in air to determine the surge immunity of the package.
- (4) Testing is carried in oil to determine the intrinsic surge immunity of the isolation barrier.
- (5) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (6) All pins on each side of the barrier are tied together, creating a two-pin device.

6.7 Safety-Related Certifications

| VDE | UL |
|---|---|
| DIN EN IEC 60747-17 (VDE 0884-17), EN IEC 60747-17, DIN EN IEC 62368-1 (VDE 0868-1), EN IEC 62368-1, IEC 62368-1 Clause : 5.4.3 ; 5.4.4.4 ; 5.4.9 | Recognized under 1577 component recognition program |
| Reinforced insulation | Single protection |
| Certificate number: 40040142 (pending) | File number: E181974 |

6.8 Safety Limiting Values

Safety limiting⁽¹⁾ intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to over-heat the die and damage the isolation barrier potentially leading to secondary system failures.

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------|---|---|-----|-----|------|------|
| I _S | Safety input, output, or supply current | R _{θJA} = 63.2°C/W, VDDx = 3.6 V, T _J = 150°C, T _A = 25°C | | | 550 | mA |
| | | R _{θJA} = 63.2°C/W, VDDx = 5.5 V, T _J = 150°C, T _A = 25°C | | | 360 | |
| P _S | Safety input, output, or total power | R _{θJA} = 63.2°C/W, T _J = 150°C, T _A = 25°C | | | 1980 | mW |
| T _S | Maximum safety temperature | | | | 150 | °C |

- (1) The maximum safety temperature, T_S, has the same value as the maximum junction temperature, T_J, specified for the device. The I_S and P_S parameters represent the safety current and safety power, respectively. Do not exceed the maximum limits of I_S and P_S. These limits vary with the ambient temperature, T_A.

The junction-to-air thermal resistance, R_{θJA}, in the [Thermal Information](#) table is that of a device installed on a high-K test board for leaded surface-mount packages. Use these equations to calculate the value for each parameter:

T_J = T_A + R_{θJA} × P, where P is the power dissipated in the device.

T_{J(max)} = T_S = T_A + R_{θJA} × P_S, where T_{J(max)} is the maximum junction temperature.

P_S = I_S × VDD_{max}, where VDD_{max} is the maximum supply voltage for high-side and low-side.

6.9 Electrical Characteristics

minimum and maximum specifications apply from $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{DD1} = 3.0\text{ V}$ to 5.5 V , $V_{DD2} = 3.0\text{ V}$ to 5.5 V , $I_{NP} = -250\text{ mV}$ to $+250\text{ mV}$, and $I_{NN} = \text{GND1}$; typical specifications are at $T_A = 25^{\circ}\text{C}$, $V_{DD1} = 5\text{ V}$, and $V_{DD2} = 3.3\text{ V}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|---|--------|--------------|-------|--------------------------------|
| ANALOG INPUT | | | | | | |
| V_{OS} | Input offset voltage ^{(1) (2)} | $T_A = 25^{\circ}\text{C}$, $I_{NP} = I_{NN} = \text{GND1}$ | -0.2 | ± 0.01 | 0.2 | mV |
| TCV_{OS} | Input offset drift ^{(1) (2) (4)} | | -0.9 | ± 0.1 | 0.9 | $\mu\text{V}/^{\circ}\text{C}$ |
| CMRR | Common-mode rejection ratio | $f_{IN} = 0\text{ Hz}$, $V_{CM\text{ min}} \leq V_{CM} \leq V_{CM\text{ max}}$ | | -100 | | dB |
| | | $f_{IN} = 10\text{ kHz}$, $V_{CM\text{ min}} \leq V_{CM} \leq V_{CM\text{ max}}$ | | -98 | | |
| R_{IN} | Single-ended input resistance | $I_{NN} = \text{GND1}$ | | 19 | | k Ω |
| R_{IND} | Differential input resistance | | | 22 | | k Ω |
| I_{IB} | Input bias current | $I_{NP} = I_{NN} = \text{GND1}$; $I_{IB} = (I_{IBP} + I_{IBN}) / 2$ | -41 | -30 | -24 | μA |
| I_{IO} | Input offset current | $I_{IO} = I_{IBP} - I_{IBN}$; $I_{NP} = I_{NN} = \text{GND1}$ | | ± 5 | | nA |
| C_{IN} | Single-ended input capacitance | $I_{NN} = \text{GND1}$, $f_{IN} = 275\text{ kHz}$ | | 2 | | pF |
| C_{IND} | Differential input capacitance | $f_{IN} = 275\text{ kHz}$ | | 1 | | pF |
| ANALOG OUTPUT | | | | | | |
| | Nominal gain | | | 8.2 | | V/V |
| E_G | Gain error ⁽¹⁾ | $T_A = 25^{\circ}\text{C}$ | -0.3% | $\pm 0.04\%$ | 0.3% | |
| TCE_G | Gain drift ^{(1) (5)} | | -30 | ± 5 | 30 | ppm/ $^{\circ}\text{C}$ |
| | Nonlinearity ⁽¹⁾ | | -0.03% | $\pm 0.01\%$ | 0.03% | |
| THD | Total harmonic distortion ⁽³⁾ | $f_{IN} = 10\text{ kHz}$ | | -85 | | dB |
| | Output noise | $I_{NP} = I_{NN} = \text{GND1}$, $f_{IN} = 0\text{ Hz}$, BW = 100 kHz brickwall filter | | 230 | | μV_{RMS} |
| SNR | Signal-to-noise ratio | $f_{IN} = 1\text{ kHz}$, BW = 10 kHz | 81.5 | 85 | | dB |
| | | $f_{IN} = 10\text{ kHz}$, BW = 100 kHz | | 72 | | |
| PSRR | Power-supply rejection ratio ⁽²⁾ | PSRR vs V_{DD1} , at DC | | -100 | | dB |
| | | PSRR vs V_{DD1} , 100-mV and 10-kHz ripple | | -96 | | |
| | | PSRR vs V_{DD2} , at DC | | -106 | | |
| | | PSRR vs V_{DD2} , 100-mV and 10-kHz ripple | | -86 | | |
| V_{CMout} | Common-mode output voltage | | 1.39 | 1.44 | 1.49 | V |
| $V_{CLIPout}$ | Clipping differential output voltage | $V_{OUT} = (V_{OUTP} - V_{OUTN})$; $ V_{IN} = V_{INP} - V_{INN} > V_{Clipping} $ | -2.52 | ± 2.49 | 2.52 | V |
| $V_{Failsafe}$ | Failsafe differential output voltage | V_{DD1} missing | -2.63 | -2.57 | -2.53 | V |
| BW | Output bandwidth | | 250 | 310 | | kHz |
| R_{OUT} | Output resistance | On OUTP or OUTN | | < 0.2 | | Ω |
| | Output short-circuit current | On OUTP or OUTN, sourcing or sinking, $I_{NN} = I_{NP} = \text{GND1}$, outputs shorted to either GND2 or V_{DD2} | | 14 | | mA |
| CMTI | Common-mode transient immunity | | 100 | 150 | | kV/ μs |

6.9 Electrical Characteristics (continued)

minimum and maximum specifications apply from $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{DD1} = 3.0\text{ V}$ to 5.5 V , $V_{DD2} = 3.0\text{ V}$ to 5.5 V , $\text{INP} = -250\text{ mV}$ to $+250\text{ mV}$, and $\text{INN} = \text{GND1}$; typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = 5\text{ V}$, and $V_{DD2} = 3.3\text{ V}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------|---------------------------------------|---|------|------|------|------|
| POWER SUPPLY | | | | | | |
| $V_{DD1_{UV}}$ | VDD1 undervoltage detection threshold | VDD1 rising | 2.5 | 2.7 | 2.9 | V |
| | | VDD1 falling | 2.4 | 2.6 | 2.8 | |
| $V_{DD2_{UV}}$ | VDD2 undervoltage detection threshold | VDD2 rising | 2.2 | 2.45 | 2.65 | V |
| | | VDD2 falling | 1.85 | 2.0 | 2.2 | |
| I_{DD1} | High-side supply current | $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$ | | 6.3 | 8.5 | mA |
| | | $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$ | | 7.2 | 9.8 | |
| I_{DD2} | Low-side supply current | $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$ | | 5.3 | 7.2 | mA |
| | | $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$ | | 5.9 | 8.1 | |

- (1) The typical value includes one standard deviation (σ) at nominal operating conditions.
- (2) This parameter is input referred.
- (3) THD is the ratio of the rms sum of the amplitudes of first five higher harmonics to the amplitude of the fundamental.
- (4) Offset error temperature drift is calculated using the box method, as described by the following equation:

$$TCV_{OS} = (Value_{MAX} - Value_{MIN}) / TempRange$$
- (5) Gain error temperature drift is calculated using the box method, as described by the following equation:

$$TCE_G (ppm) = (Value_{MAX} - Value_{MIN}) / (Value_{(T=25^\circ\text{C})} \times TempRange) \times 10^6$$

6.10 Switching Characteristics

over operating ambient temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|--|--|-----|-----|-----|---------------|
| t_r | Output signal rise time | | | 1.3 | | μs |
| t_f | Output signal fall time | | | 1.3 | | μs |
| | V_{INx} to V_{OUTx} signal delay (50% - 10%) | Unfiltered output | | 1 | 1.5 | μs |
| | V_{INx} to V_{OUTx} signal delay (50% - 50%) | Unfiltered output | | 1.6 | 2.1 | μs |
| | V_{INx} to V_{OUTx} signal delay (50% - 90%) | Unfiltered output | | 2.5 | 3 | μs |
| t_{AS} | Analog settling time | VDD1 step to 3.0 V with $V_{DD2} \geq 3.0\text{ V}$, to V_{OUTP} , V_{OUTN} valid, 0.1% settling | | 500 | | μs |

6.11 Timing Diagram

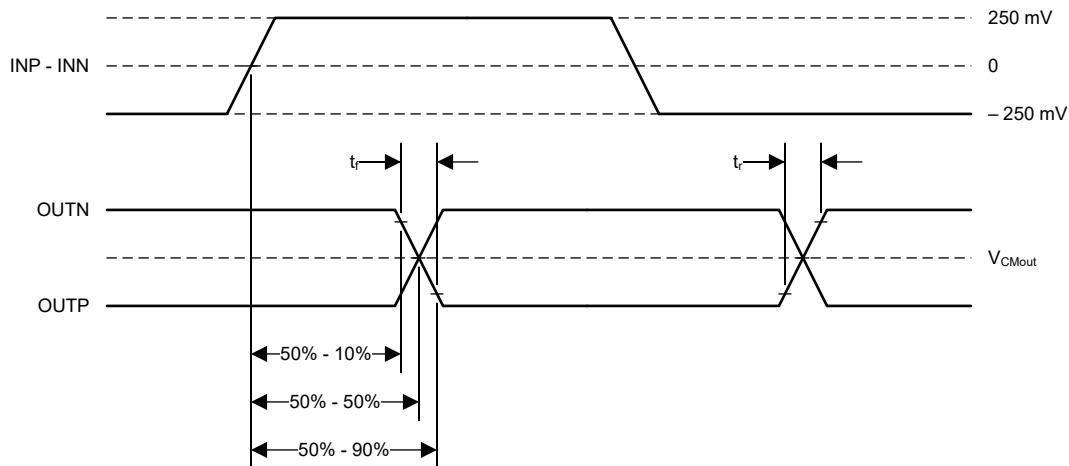


Figure 6-1. Rise, Fall, and Delay Time Definition

6.12 Insulation Characteristics Curves

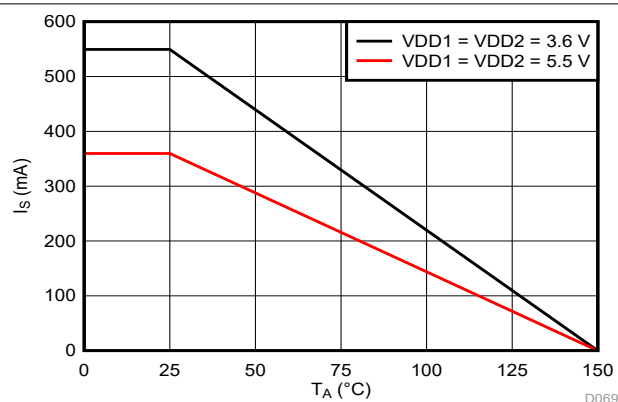


Figure 6-2. Thermal Derating Curve for Safety-Limiting Current per VDE

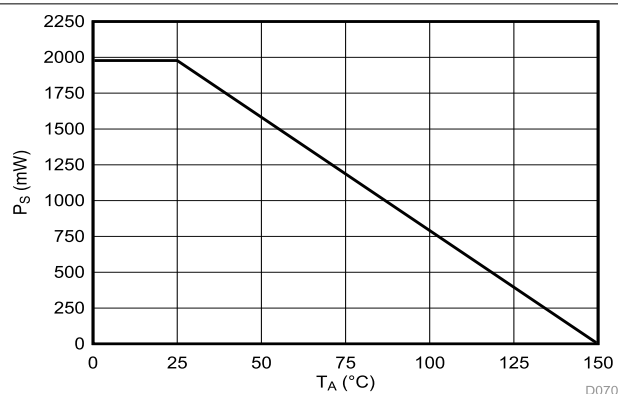
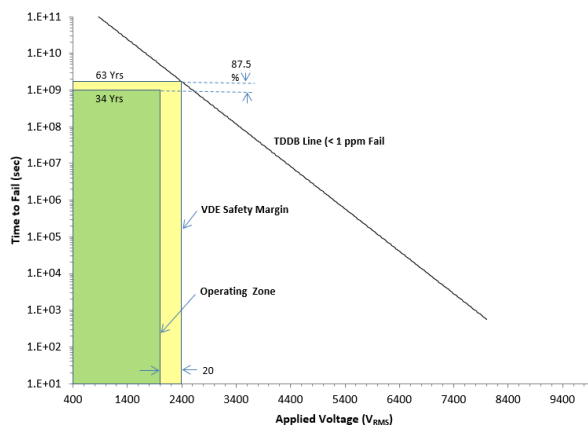


Figure 6-3. Thermal Derating Curve for Safety-Limiting Power per VDE



T_A up to 150°C, stress-voltage frequency = 60 Hz, isolation working voltage = 2000 V_{RMS} , operating lifetime = 34 year

Figure 6-4. Reinforced Isolation Capacitor Lifetime Projection

6.13 Typical Characteristics

at VDD1 = 5 V, VDD2 = 3.3 V, INP = -250 mV to 250 mV, INN = 0 V, and $f_{IN} = 10$ kHz (unless otherwise noted)

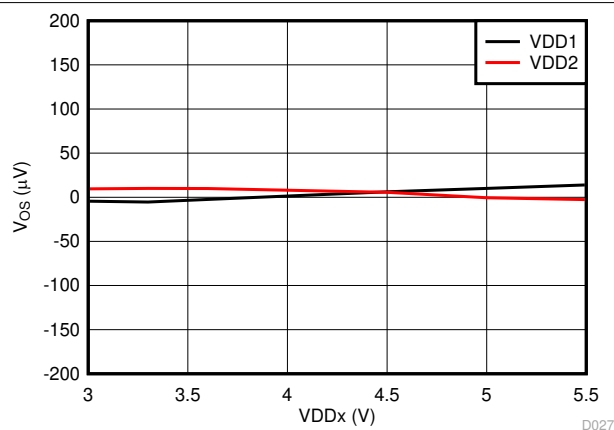


Figure 6-5. Input Offset Voltage vs Supply Voltage

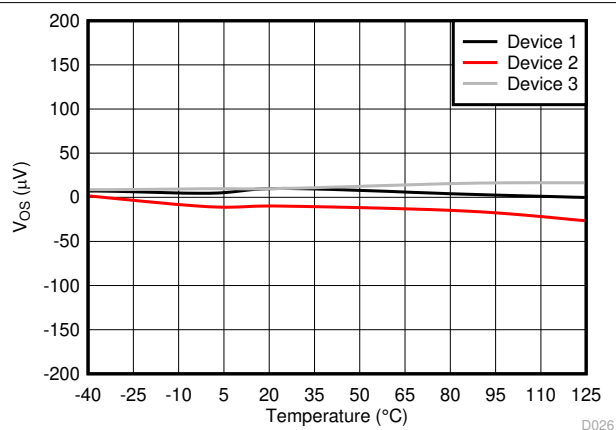


Figure 6-6. Input Offset Voltage vs Temperature

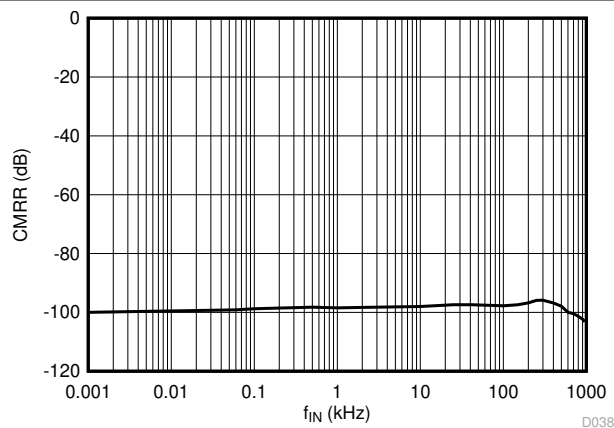


Figure 6-7. Common-Mode Rejection Ratio vs Input Frequency

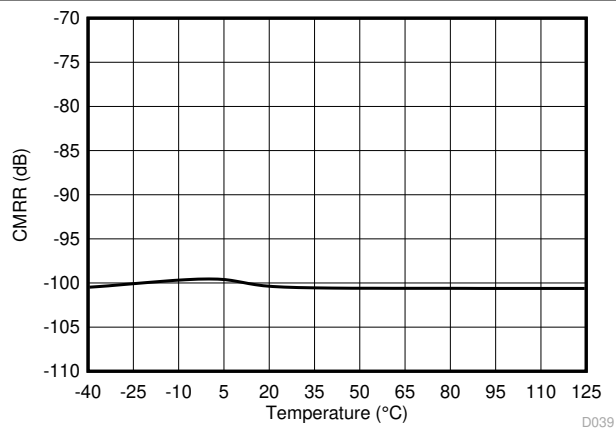


Figure 6-8. Common-Mode Rejection Ratio vs Temperature

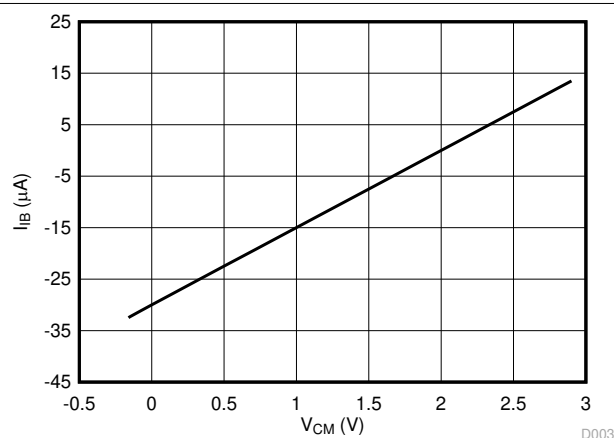


Figure 6-9. Input Bias Current vs Common-Mode Input Voltage

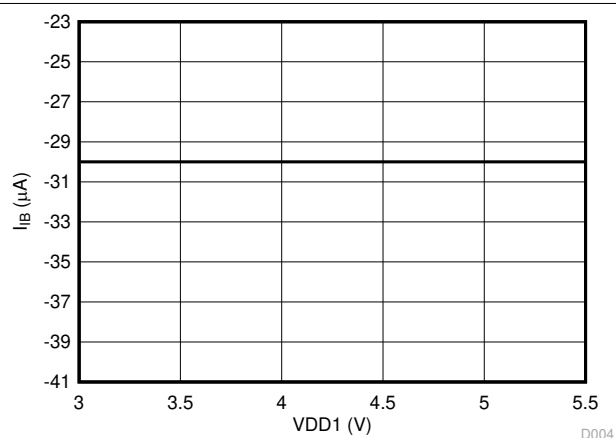


Figure 6-10. Input Bias Current vs High-Side Supply Voltage

6.13 Typical Characteristics (continued)

at VDD1 = 5 V, VDD2 = 3.3 V, INP = -250 mV to 250 mV, INN = 0 V, and $f_{IN} = 10$ kHz (unless otherwise noted)

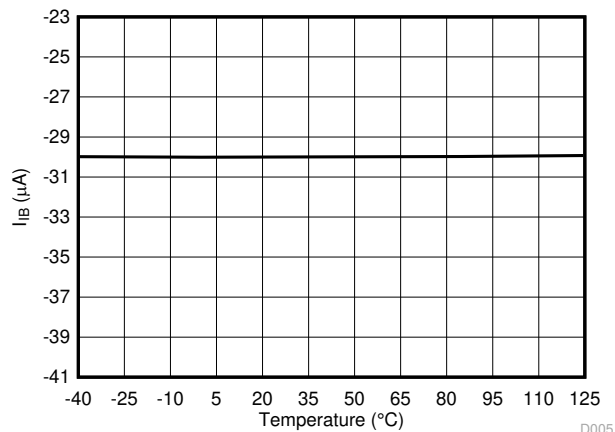


Figure 6-11. Input Bias Current vs Temperature

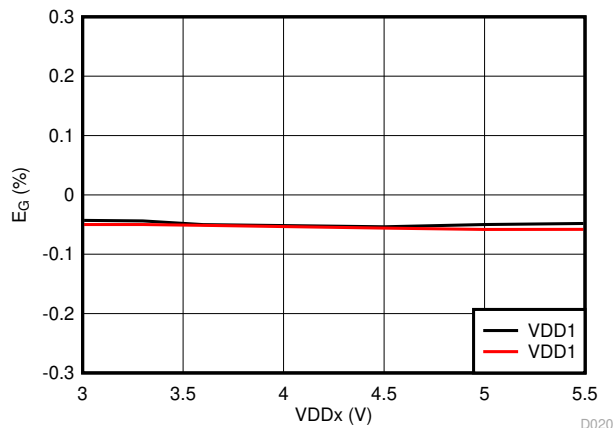


Figure 6-12. Gain Error vs Supply Voltage

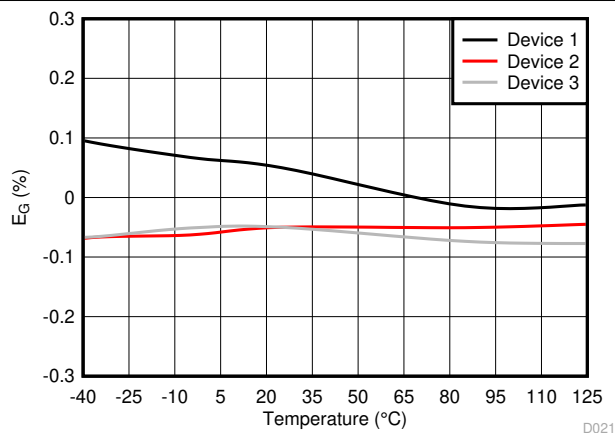


Figure 6-13. Gain Error vs Temperature

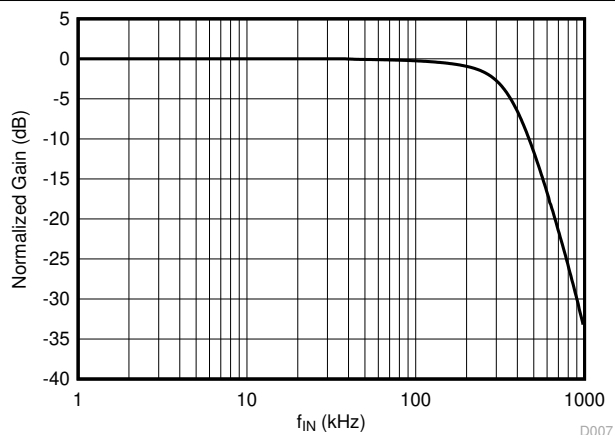


Figure 6-14. Normalized Gain vs Input Frequency

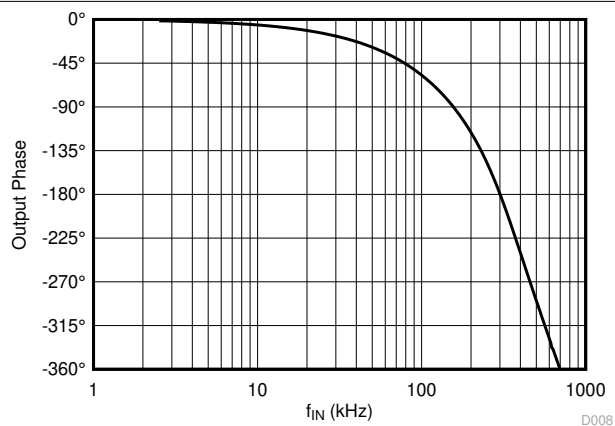


Figure 6-15. Output Phase vs Input Frequency

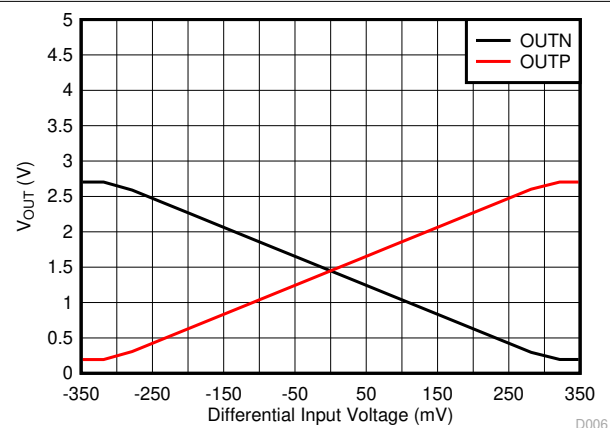


Figure 6-16. Output Voltage vs Input Voltage

6.13 Typical Characteristics (continued)

at VDD1 = 5 V, VDD2 = 3.3 V, INP = -250 mV to 250 mV, INN = 0 V, and $f_{IN} = 10$ kHz (unless otherwise noted)

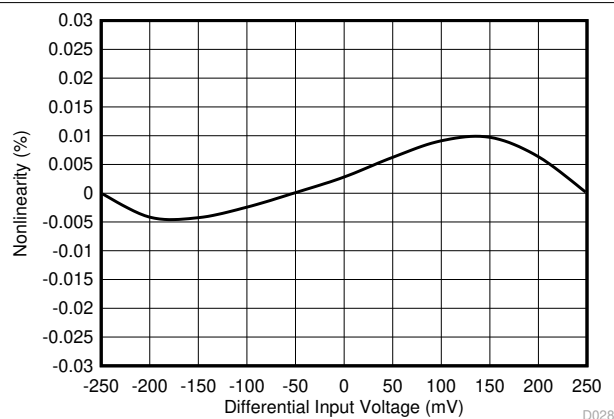


Figure 6-17. Nonlinearity vs Input Voltage

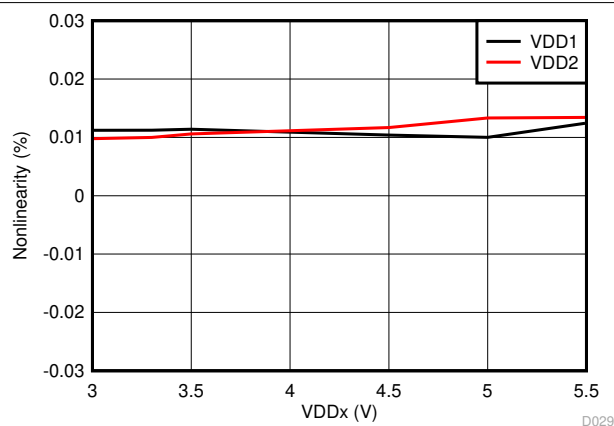


Figure 6-18. Nonlinearity vs Supply Voltage

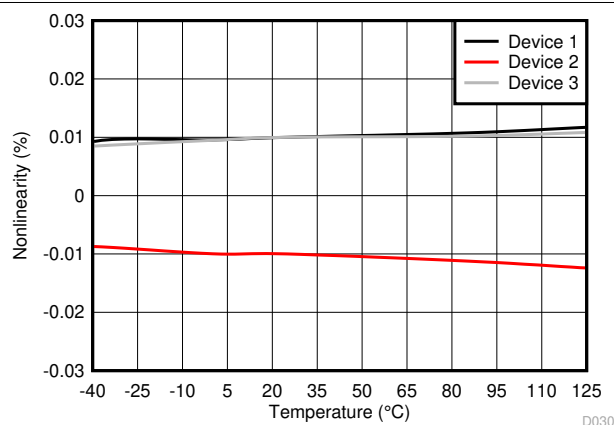


Figure 6-19. Nonlinearity vs Temperature

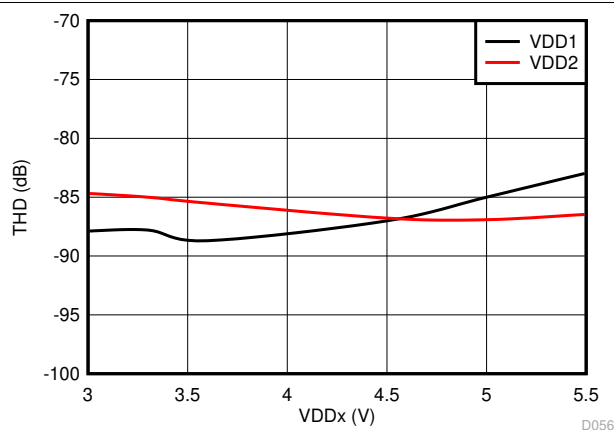


Figure 6-20. Total Harmonic Distortion vs Supply Voltage

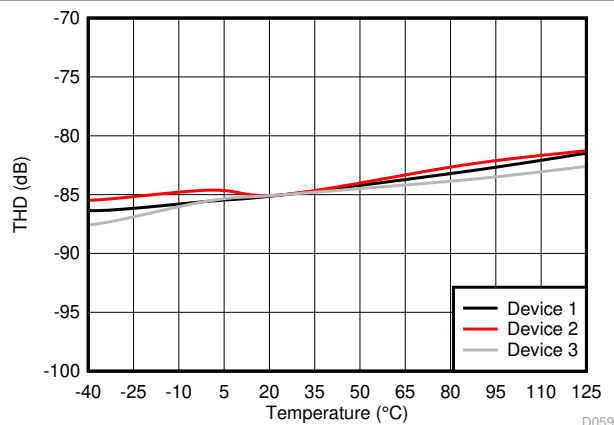


Figure 6-21. Total Harmonic Distortion vs Temperature

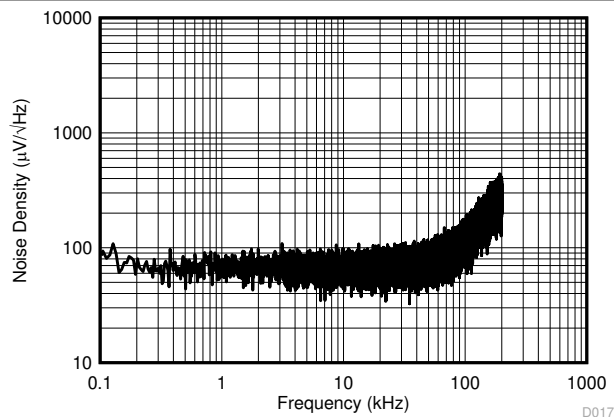


Figure 6-22. Input-Referred Noise Density vs Frequency

6.13 Typical Characteristics (continued)

at VDD1 = 5 V, VDD2 = 3.3 V, INP = -250 mV to 250 mV, INN = 0 V, and $f_{IN} = 10$ kHz (unless otherwise noted)

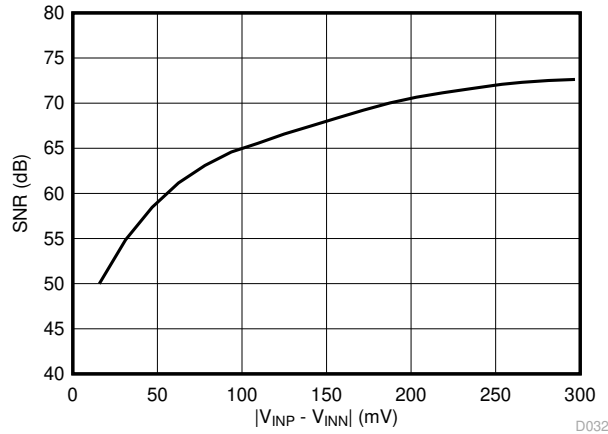


Figure 6-23. Signal-to-Noise Ratio vs Input Voltage

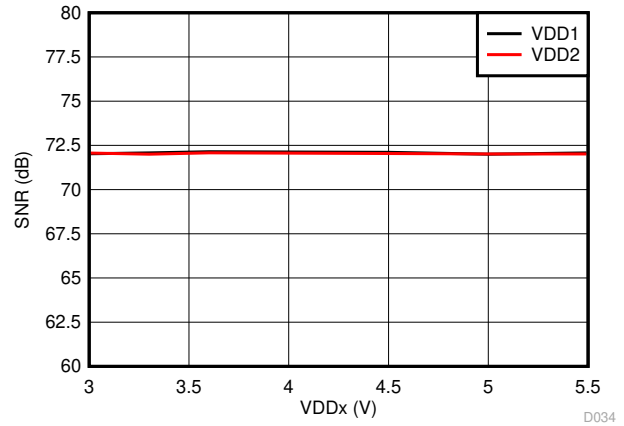


Figure 6-24. Signal-to-Noise Ratio vs Supply Voltage

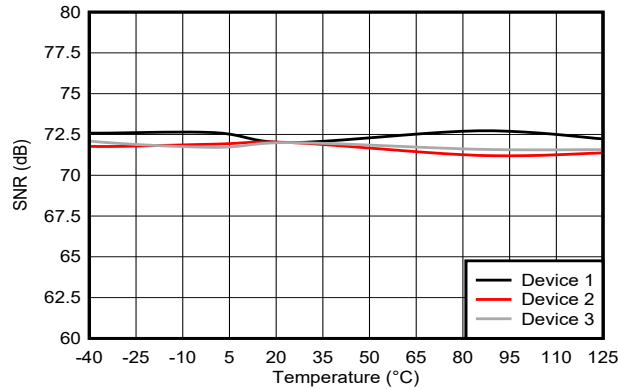


Figure 6-25. Signal-to-Noise Ratio vs Temperature

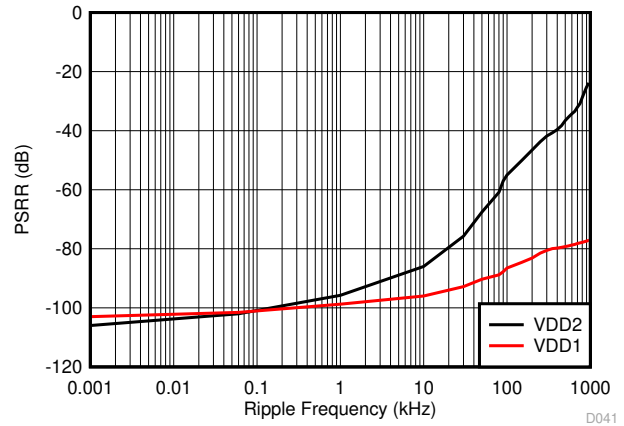


Figure 6-26. Power-Supply Rejection Ratio vs Ripple Frequency

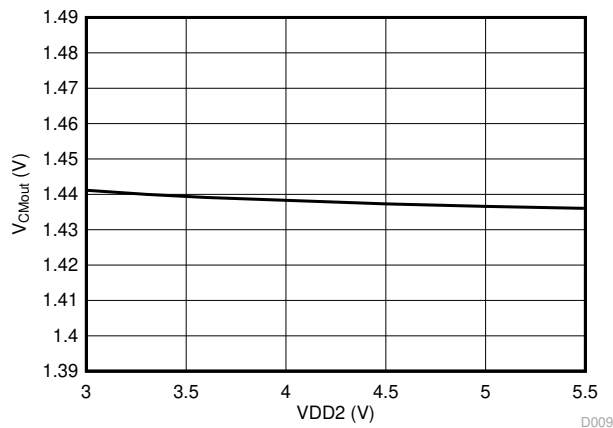


Figure 6-27. Output Common-Mode Voltage vs Low-Side Supply Voltage

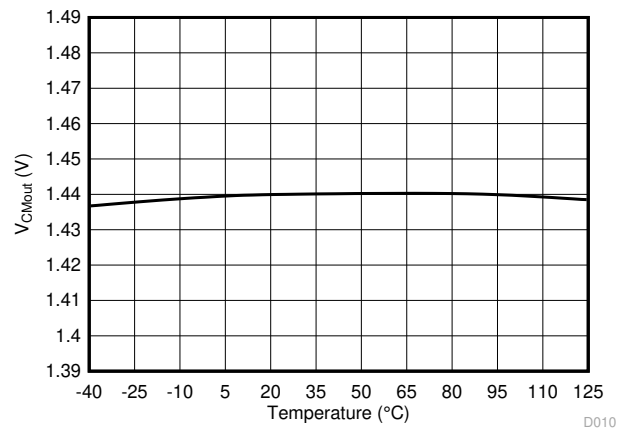


Figure 6-28. Output Common-Mode Voltage vs Temperature

6.13 Typical Characteristics (continued)

at VDD1 = 5 V, VDD2 = 3.3 V, INP = -250 mV to 250 mV, INN = 0 V, and $f_{IN} = 10$ kHz (unless otherwise noted)

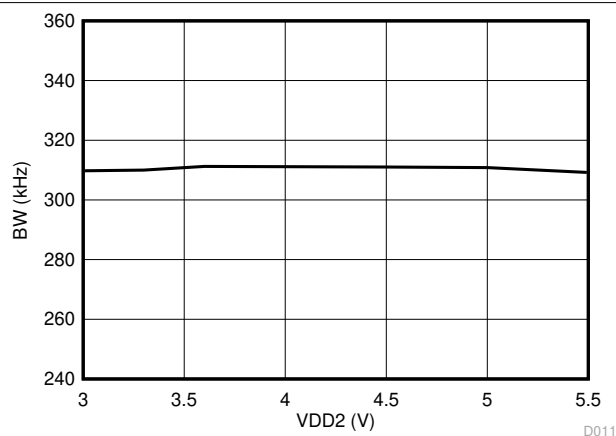


Figure 6-29. Output Bandwidth vs Low-Side Supply Voltage

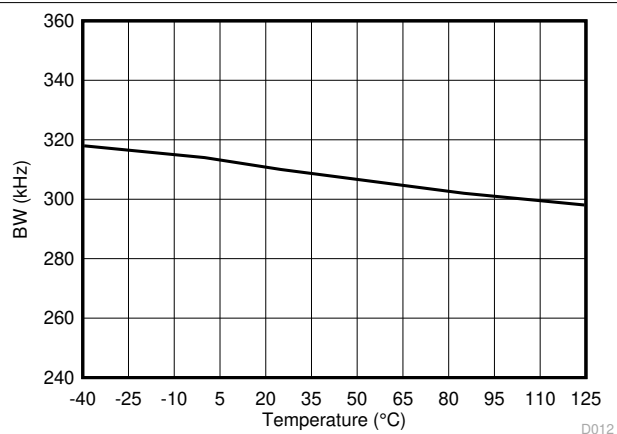


Figure 6-30. Output Bandwidth vs Temperature

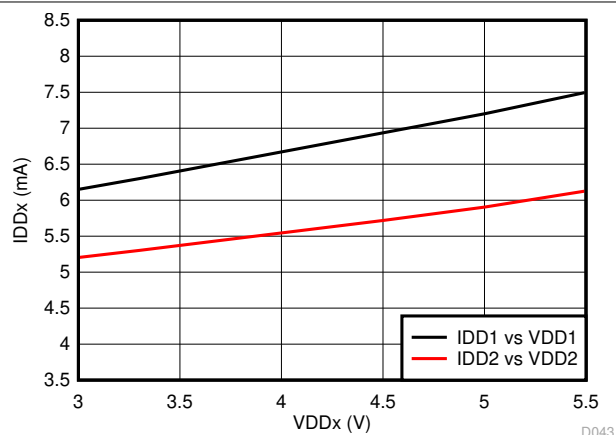


Figure 6-31. Supply Current vs Supply Voltage

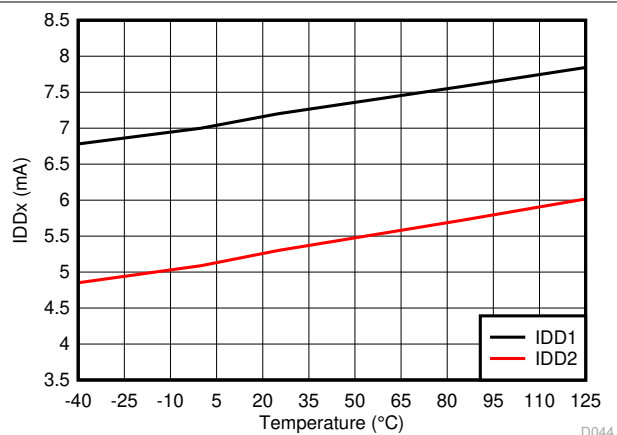


Figure 6-32. Supply Current vs Temperature

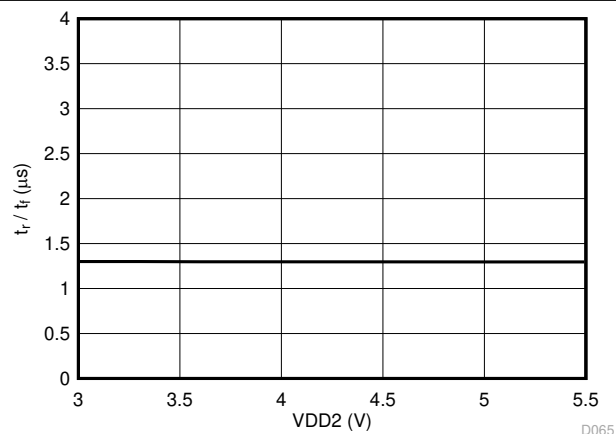


Figure 6-33. Output Rise and Fall Time vs Low-Side Supply

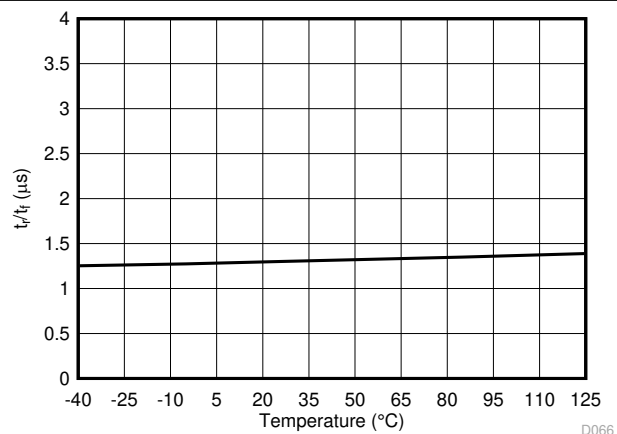


Figure 6-34. Output Rise and Fall Time vs Temperature

6.13 Typical Characteristics (continued)

at VDD1 = 5 V, VDD2 = 3.3 V, INP = -250 mV to 250 mV, INN = 0 V, and f_{IN} = 10 kHz (unless otherwise noted)

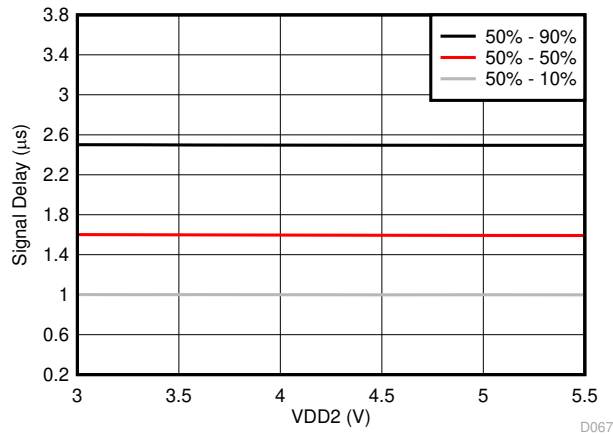


Figure 6-35. V_{IN} to V_{OUT} Signal Delay vs Low-Side Supply Voltage

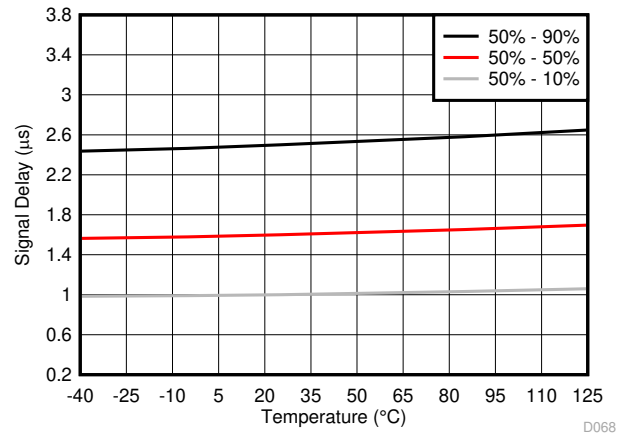


Figure 6-36. V_{IN} to V_{OUT} Signal Delay vs Temperature

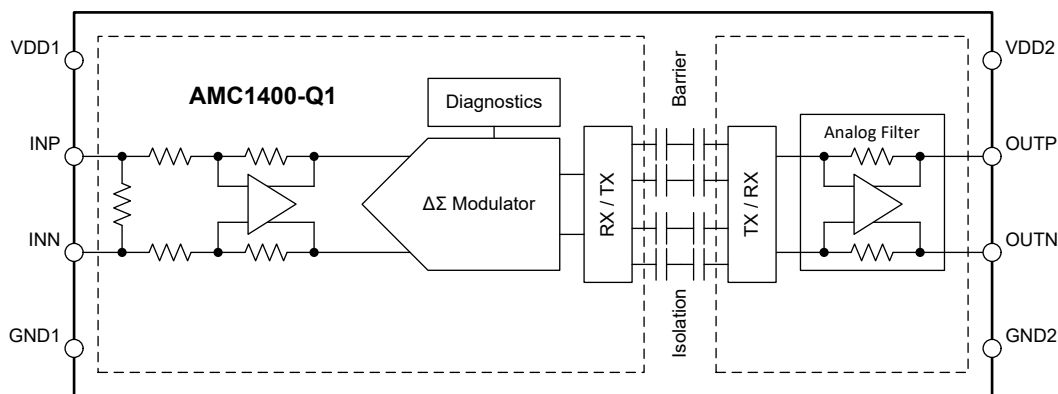
7 Detailed Description

7.1 Overview

The AMC1400-Q1 is a fully differential, precision, isolated amplifier. The input stage of the device consists of a fully differential amplifier that drives a second-order, delta-sigma ($\Delta\Sigma$) modulator. The modulator converts the analog input signal into a digital bitstream that is transferred across the isolation barrier that separates the high-side from the low-side. On the low-side, the received bitstream is processed by a fourth-order analog filter that outputs a differential signal at the OUTP and OUTN pins that is proportional to the input signal.

The SiO₂-based, capacitive isolation barrier supports a high level of magnetic field immunity, as described in the [ISO72x Digital Isolator Magnetic-Field Immunity application report](#). The digital modulation used in the AMC1400-Q1 to transmit data across the isolation barrier, and the isolation barrier characteristics itself, result in high reliability and common-mode transient immunity.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Analog Input

The differential amplifier input stage of the AMC1400-Q1 feeds a second-order, switched-capacitor, feed-forward $\Delta\Sigma$ modulator. The gain of the differential amplifier is set by internal precision resistors with a differential input impedance of R_{IND} . The modulator converts the analog input signal into a bitstream that is transferred across the isolation barrier, as described in the [Isolation Channel Signal Transmission](#) section.

There are two restrictions on the analog input signals INP and INN. First, if the input voltages V_{INP} or V_{INN} exceed the range specified in the [Absolute Maximum Ratings](#) table, the input currents must be limited to the absolute maximum value, because the electrostatic discharge (ESD) protection turns on. In addition, the linearity and parametric performance of the device are ensured only when the analog input voltage remains within the linear full-scale range (V_{FSR}) and within the common-mode input voltage range (V_{CM}), as specified in the [Recommended Operating Conditions](#) table.

7.3.2 Isolation Channel Signal Transmission

The AMC1400-Q1 uses an on-off keying (OOK) modulation scheme, as shown in [Figure 7-1](#), to transmit the modulator output bitstream across the SiO₂-based isolation barrier. The transmit driver (TX) shown in the [Functional Block Diagram](#) transmits an internally-generated, high-frequency carrier across the isolation barrier to represent a digital *one* and does not send a signal to represent a digital *zero*. The nominal frequency of the carrier used inside the AMC1400-Q1 is 480 MHz.

The receiver (RX) on the other side of the isolation barrier recovers and demodulates the signal and provides the input to the fourth-order analog filter. The AMC1400-Q1 transmission channel is optimized to achieve the highest level of common-mode transient immunity (CMTI) and lowest level of radiated emissions caused by the high-frequency carrier and RX/TX buffer switching.

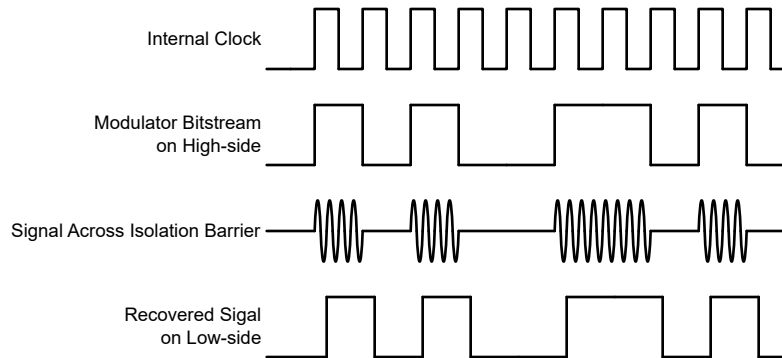


Figure 7-1. OOK-Based Modulation Scheme

7.3.3 Analog Output

The AMC1400-Q1 offers a differential analog output comprised of the OUTP and OUTN pins. For differential input voltages ($V_{INP} - V_{INN}$) in the range from -250 mV to $+250\text{ mV}$, the device provides a linear response with a nominal gain of 8.2. For example, for a differential input voltage of 250 mV , the differential output voltage ($V_{OUTP} - V_{OUTN}$) is 2.05 V . At zero input (INP shorted to INN), both pins output the same common-mode output voltage V_{CMout} , as specified in the [Electrical Characteristics](#) table. For absolute differential input voltages greater than 250 mV but less than 320 mV , the differential output voltage continues to increase in magnitude but with reduced linearity performance. The outputs saturate at a differential output voltage of $V_{CLIPout}$, as shown in [Figure 7-2](#), if the differential input voltage exceeds the $V_{Clipping}$ value.

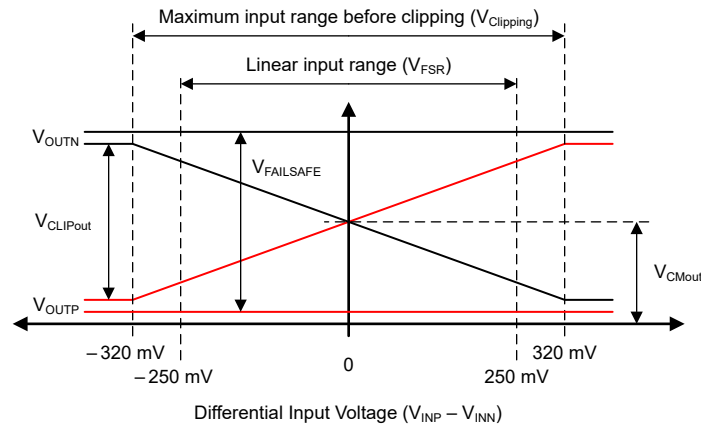


Figure 7-2. Output Behavior of the AMC1400-Q1

The AMC1400-Q1 offers a fail-safe feature that simplifies diagnostics on a system level. [Figure 7-2](#) shows the fail-safe mode, in which the AMC1400-Q1 outputs a negative differential output voltage that does not occur under normal operating conditions. The fail-safe output is active in two cases:

- When the high-side supply is missing or below the $V_{DD1_{UV}}$ threshold
- When the common-mode input voltage, that is $V_{CM} = (V_{INP} + V_{INN}) / 2$, exceeds the common-mode overvoltage detection level V_{CMov}

Use the maximum $V_{FAILSAFE}$ voltage specified in the [Electrical Characteristics](#) table as a reference value for fail-safe detection on a system level.

7.4 Device Functional Modes

The AMC1400-Q1 is operational when the power supplies V_{DD1} and V_{DD2} are applied, as specified in the [Recommended Operating Conditions](#) table.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

With its stretched SOIC package, the AMC1400-Q1 is specifically designed for isolated, high precision, shunt-based current sensing in applications with 800-V and higher working voltages. This device is designed for operating in harsh environments with a high pollution degree or high altitudes.

8.2 Typical Application

[Figure 8-1](#) depicts a simplified block diagram of a DC/DC converter for an 800-V battery system where the AMC1400-Q1 is used to measure the input current on the high-voltage side. The DC bus current flows through a shunt resistor (RSHUNT) and produces a voltage drop that is sensed by the AMC1400-Q1. The AMC1400-Q1 outputs a differential analog voltage that is proportional to the input signal and galvanically isolated from the high-voltage side. The differential output voltage is typically routed to an analog-to-digital converter (ADC) of a microcontroller (MCU) to complete the current-sensing signal chain. The [AMC1411-Q1](#) is used in the same application for measuring the DC bus voltage. Both devices share a common high-side power supply based on the [SN6501-Q1](#) push-pull driver and a transformer that supports the desired isolation voltage ratings.

The stretched SOIC package, differential input, differential output, and the high common-mode transient immunity (CMTI) of the AMC1400-Q1 ensure reliable and accurate operation in high-noise environments while meeting IEC standards for reinforced isolation at 1 kV and higher working voltages.

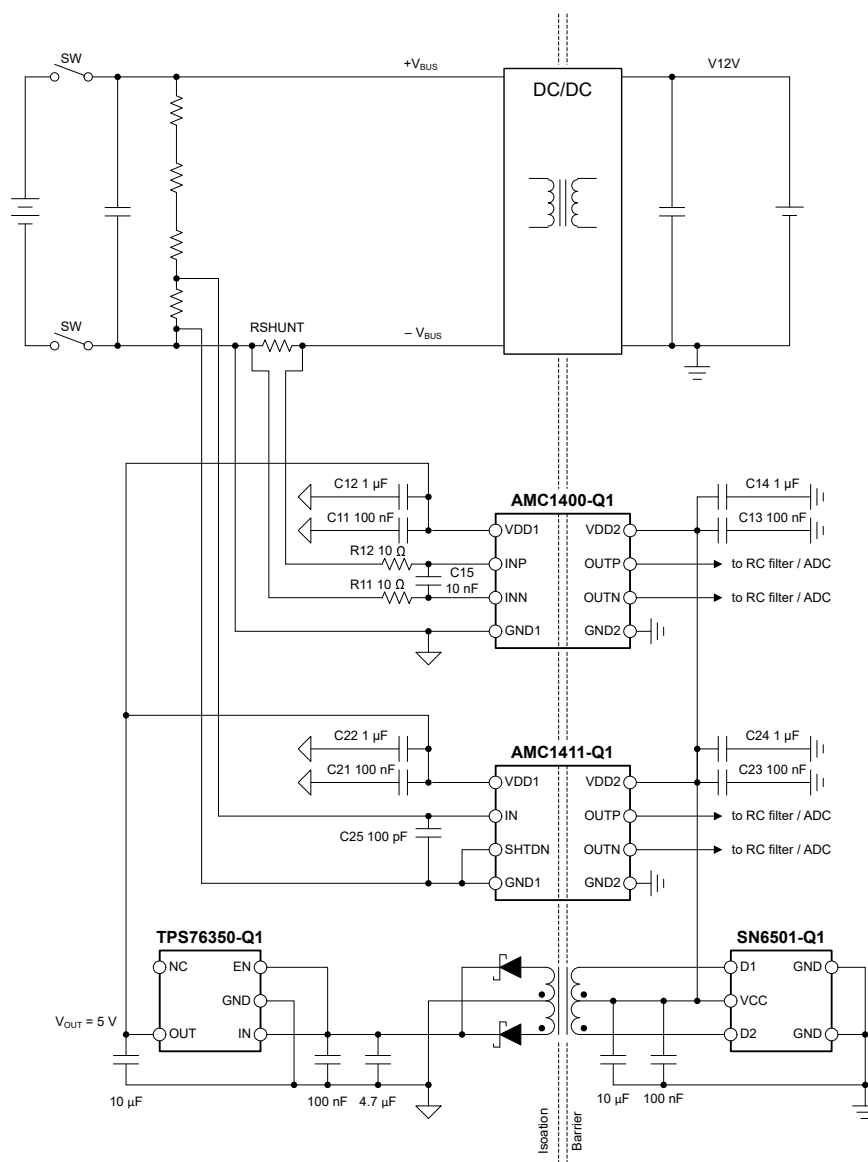


Figure 8-1. Using the AMC1400-Q1 for Current Sensing in a Typical Application

8.2.1 Design Requirements

Table 8-1 lists the parameters for this typical application.

Table 8-1. Design Requirements

| PARAMETER | VALUE |
|--|-------------------|
| DC bus voltage | 1000 V (maximum) |
| Overvoltage category | II |
| Pollution degree | 2 |
| Altitude | ≤4000 m |
| High-side supply voltage | 3.3 V or 5 V |
| Low-side supply voltage | 3.3 V or 5 V |
| Transient peak DC/DC input current | 10 A |
| Nominal DC/DC input current | 4 A |
| Voltage drop across RSHUNT for a linear response | ±250 mV (maximum) |
| Maximum voltage drop across RSHUNT before clipping | ±320 mV (maximum) |

8.2.2 Detailed Design Procedure

The value of the shunt resistor (RSHUNT) is selected such that the transient peak input current to the DC/DC converter (10 A) produces a voltage drop across the shunt resistor that matches the linear full-scale input range of the AMC1400-Q1 (250 mV). Consider the following two restrictions when selecting the value of the shunt resistor:

- The voltage drop across the shunt caused by the nominal-rated DC link current range must not exceed the recommended differential input voltage range for a linear response: $|V_{SHUNT}| \leq |V_{FSR}|$
- The voltage drop caused by the maximum allowed overcurrent must not exceed the input voltage that causes a clipping output: $|V_{SHUNT}| \leq |V_{Clipping}|$

In this example, a 25-mΩ shunt resistor is selected ($R_{SHUNT} = 250 \text{ mV} / 10 \text{ A}$).

At the nominal-rated current, the power dissipation in the shunt resistor is $R \times I^2 = 25 \text{ m}\Omega \times (4 \text{ A})^2 = 0.4 \text{ W}$. For surface-mounted shunts, the heat is mainly dissipated via the device terminals and the printed circuit board (PCB) traces. The power rating of a shunt is typically specified for a 70°C terminal temperature and derated for higher temperatures. This rating ensures that the shunt itself does not exceed its specified maximum operating temperature at the rated power dissipation. Careful PCB design is required not to exceed the terminal temperature at the rated power dissipation. Using wide copper traces to spread the heat over a larger area of the PCB, heat sinks, and air flow can improve the thermal design.

8.2.2.1 Insulation Coordination

Electrical insulation must be designed to withstand the rated impulse voltage, temporary overvoltage, and the working voltage. In addition, the physical distance between exposed metal parts on the high- and low-voltage sides must meet the minimum creepage and clearance requirements for the rated working voltage and transient overvoltages.

The ISO 17409:2020 standard specifies that an electrical road vehicle must be designed to withstand a minimum impulse voltage of 2500 V. The minimum *clearance* to support a 2500-V impulse voltage is 1.5 mm for basic isolation and 3.0 mm for reinforced isolation, according to Table F.2 of the IEC60664-1 standard. The equipment is designed to operate at altitudes up to 4000 m above sea level and the minimum clearance must be increased to $1.29 \times 3 \text{ mm} = 4 \text{ mm}$ (rounded up). The factor of 1.29 is taken from table A.2 of the IEC60664-1 standard. The AMC1400-Q1 provides a minimum clearance of 14.7 mm and easily meets the requirement.

The maximum temporary overvoltage, a voltage that must be sustained for 60 s, is typically determined by the formula $2 \times V_{WM} + 1000 \text{ V}$, where V_{WM} is the maximum working voltage that can occur under normal operating conditions. In this example, V_{WM} equals the maximum DC bus voltage (1000 V) and the maximum temporary overvoltage is calculated to be 3000 V_{PK} ($2 \times 1000 \text{ V} + 1000 \text{ V} = 3000 \text{ V}$). If the overvoltage test (also known as the *HiPot test*) is performed for 1 s only, the test voltage must be multiplied with a factor of 1.2 times and becomes 3600 V ($1.2 \times 3000 \text{ V} = 3600 \text{ V}$). The minimum *clearance* to support a 3600-V temporary overvoltage is 5.5 mm for basic isolation and 8.0 mm for reinforced isolation. These values are taken from Table 9 of the IEC61800-5-1 standard. The equipment is designed to operate at altitudes up to 4000 m above sea level and the minimum clearance must be increased to $1.29 \times 8 \text{ mm} = 10.5 \text{ mm}$ (rounded up). The factor of 1.29 is taken from Table A.2 of the IEC60664-1 standard. The AMC1400-Q1 provides a minimum clearance of 14.7 mm and easily meets the requirement.

The working voltage in this example is 1000 V_{DC} and is lower than the maximum working voltage (V_{IOWM}) of 2800 V_{DC}) that the AMC1400-Q1 supports.

Finally, the minimum *creepage* distance for a working voltage of 1000 V_{DC}, insulating material group I, pollution degree 2, and reinforced isolation is $2 \times 5 \text{ mm} = 10 \text{ mm}$ according to IEC60664-1 Table F.4. The 5-mm value for the 1000-V basic insulation is doubled for reinforced isolation. The AMC1400-Q1 provides a minimum creepage of 15.7 mm and provides significant margin against the minimum requirement.

8.2.2.2 Input Filter Design

Place an RC filter in front of the isolated amplifier to improve the signal-to-noise performance of the signal path. Design the input filter such that:

- The cutoff frequency of the filter is at least one order of magnitude lower than the sampling frequency (20 MHz) of the $\Delta\Sigma$ modulator
- The input bias current does not generate a significant voltage drop across the DC impedance of the input filter
- The impedances measured from the analog inputs are equal

For most applications, the structure shown in Figure 8-2 achieves excellent performance.

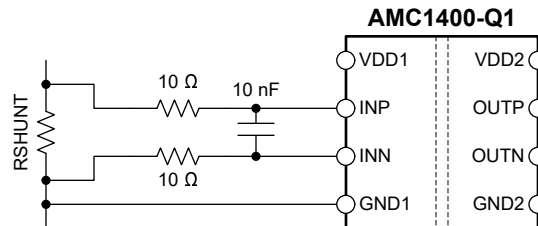


Figure 8-2. Differential Input Filter

8.2.2.3 Differential to Single-Ended Output Conversion

Figure 8-3 shows an example of a TLV9001-Q1-based signal conversion and filter circuit for systems using single-ended input ADCs to convert the analog output voltage into digital. With $R1 = R2 = R3 = R4$, the output voltage equals $(V_{OUTP} - V_{OUTN}) + V_{REF}$. Tailor the bandwidth of this filter stage to the bandwidth requirement of the system and use NP0-type capacitors for best performance. For most applications, $R1 = R2 = R3 = R4 = 3.3\text{ k}\Omega$ and $C1 = C2 = 330\text{ pF}$ yields good performance.

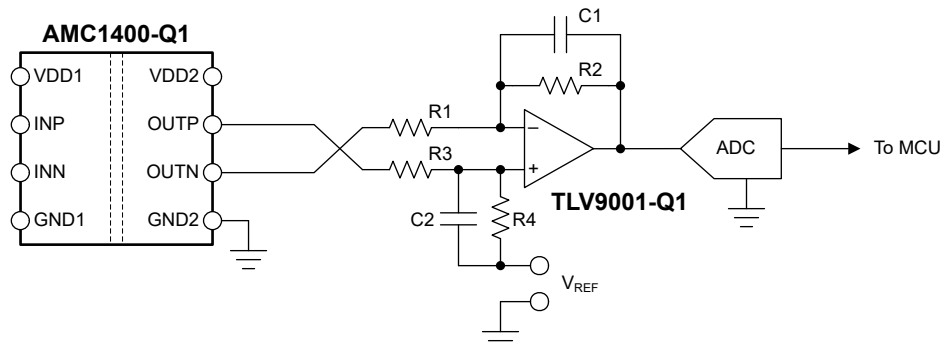


Figure 8-3. Connecting the AMC1400-Q1 Output to a Single-Ended Input ADC

For more information on the general procedure to design the filtering and driving stages of SAR ADCs, see the [18-Bit, 1MSPS Data Acquisition Block \(DAQ\) Optimized for Lowest Distortion and Noise](#) and [18-Bit Data Acquisition Block \(DAQ\) Optimized for Lowest Power reference guides](#), available for download at www.ti.com.

8.2.3 Application Curve

One important aspect of a power-stage design is the effective detection of an overcurrent condition to protect the switching devices and passive components from damage. To power off the system quickly in the event of an overcurrent condition, a low delay caused by the isolated amplifier is required. Figure 8-4 shows the typical full-scale step response of the AMC1400-Q1.

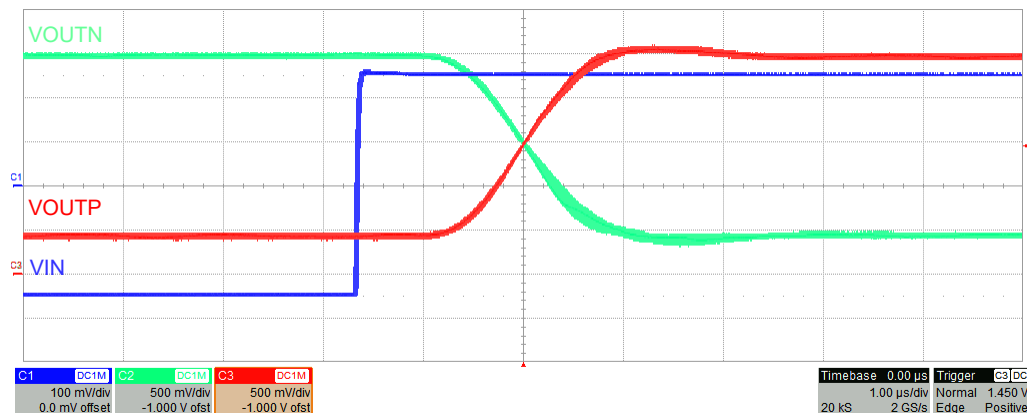


Figure 8-4. Step Response of the AMC1400-Q1

8.3 Best Design Practices

Do not leave the inputs of the AMC1400-Q1 unconnected (floating) when the device is powered up. If the device inputs are left floating, the input bias current may drive the inputs to a positive value that exceeds the operating common-mode input voltage and the output voltage may not be valid.

Connect the high-side ground (GND1) to INN, either by a hard short or through a resistive path. A DC current path between INN and GND1 is required to define the input common-mode voltage. Take care not to exceed the input common-mode range, as specified in the [Recommended Operating Conditions](#) table. For best accuracy, route the ground connection as a separate trace that connects directly to the shunt resistor rather than shorting GND1 to INN directly at the input to the device. See the [Layout](#) section for more details.

8.4 Power Supply Recommendations

The AMC1400-Q1 does not require any specific power-up sequencing. The high-side power supply (VDD1) is decoupled with a low-ESR, 100-nF capacitor (C1) parallel to a low-ESR, 1- μ F capacitor (C2). The low-side power supply (VDD2) is equally decoupled with a low-ESR, 100-nF capacitor (C3) parallel to a low-ESR, 1- μ F capacitor (C4). Place all four capacitors (C1, C2, C3, and C4) as close to the device as possible.

The ground reference for the high-side (GND1) is derived from the end of the shunt resistor, which is connected to the negative input (INN) of the device. For best DC accuracy, use a separate trace (as shown in [Figure 8-5](#)) to make this connection instead of shorting GND1 to INN directly at the device input. If a four-terminal shunt is used, the device inputs are connected to the inner leads and GND1 is connected to the outer lead on the INN-side of the shunt.

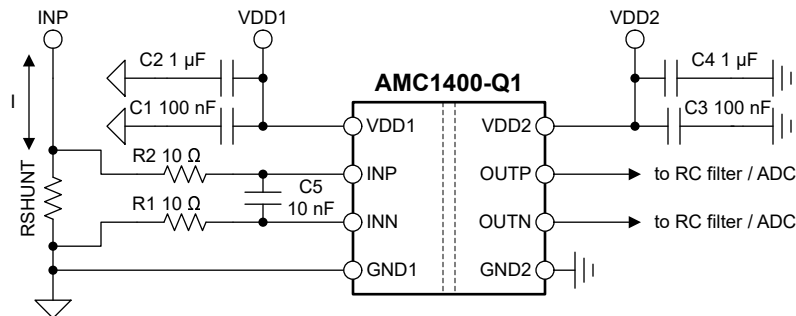


Figure 8-5. Decoupling of the AMC1400-Q1

Capacitors must provide adequate effective capacitance under the applicable DC bias conditions they experience in the application. Multilayer ceramic capacitors (MLCCs) typically exhibit only a fraction of their nominal capacitance under real-world conditions and this factor must be taken into consideration when selecting these capacitors. This problem is especially acute in low-profile capacitors, in which the dielectric field strength is higher than in taller components. Reputable capacitor manufacturers provide capacitance versus DC bias curves that greatly simplify component selection.

8.5 Layout

8.5.1 Layout Guidelines

Figure 8-6 shows a layout recommendation with the critical placement of the decoupling capacitors (as close as possible to the AMC1400-Q1 supply pins) and placement of the other components required by the device. For best performance, place the shunt resistor close to the INP and INN inputs of the AMC1400-Q1 and keep the layout of both connections symmetrical.

The ground pin (GND1) of the AMC1400-Q1 is connected to the same end of the shunt resistor that is connected to the negative input pin (INN) of the AMC1400-Q1. If a four-pin shunt is used, the input pins (INN and INP) of the AMC1400-Q1 are connected to the inner leads, and the GND1 pin is connected to the outer lead on the INN-side of the shunt resistor. To minimize offset and improve accuracy, route the ground connection as a separate trace that connects directly to the shunt resistor rather than shorting GND1 to INN directly at the input to the device.

8.5.2 Layout Example

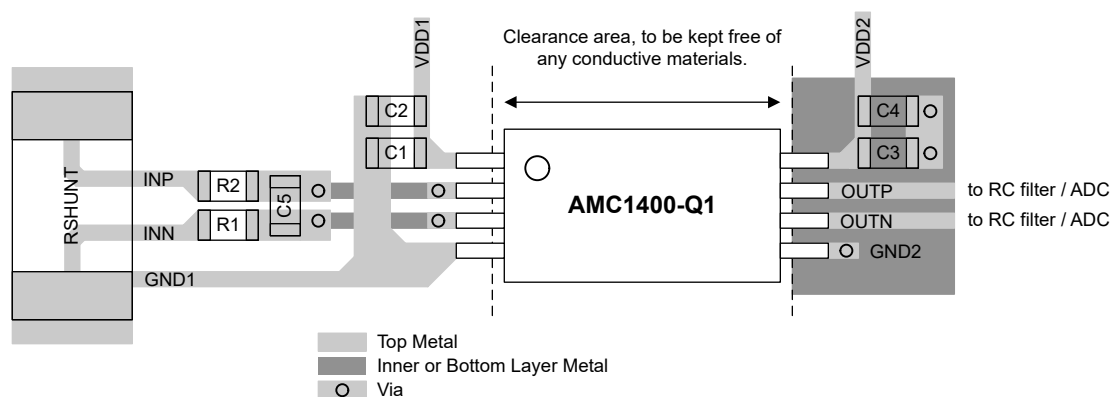


Figure 8-6. Recommended Layout of the AMC1400-Q1

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Isolation Glossary](#) application note
- Texas Instruments, [Semiconductor and IC Package Thermal Metrics](#) application note
- Texas Instruments, [ISO72x Digital Isolator Magnetic-Field Immunity](#) application note
- Texas Instruments, [TLV900x-Q1 Low-Power RRIO 1-MHz Automotive Operational Amplifier](#) data sheet
- Texas Instruments, [TPS763xx-Q1 Low-Power, 150-mA, Low-Dropout Linear Regulators](#) data sheet
- Texas Instrument, [SN6501-Q1 Transformer Driver for Isolated Power Supplies](#) data sheet
- Texas Instruments, [18-Bit, 1-MSPS Data Acquisition Block \(DAQ\) Optimized for Lowest Distortion and Noise](#) reference guide
- Texas Instruments, [18-Bit, 1-MSPS Data Acquisition Block \(DAQ\) Optimized for Lowest Power](#) reference guide
- Texas Instruments, [Isolated Amplifier Voltage Sensing Excel Calculator](#) design tool
- Texas Instruments, [Best in Class Radiated Emissions EMI Performance with the AMC1300B-Q1 Isolated Amplifier](#) technical white paper

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|--------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| AMC1400QDWLRQ1 | Active | Production | SOIC (DWL) 8 | 500 LARGE T&R | Yes | NIPDAU | Level-3-260C-168 HR | -40 to 125 | 1400Q |
| AMC1400QDWLRQ1.A | Active | Production | SOIC (DWL) 8 | 500 LARGE T&R | Yes | NIPDAU | Level-3-260C-168 HR | -40 to 125 | 1400Q |

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF AMC1400-Q1 :

- Catalog : [AMC1400](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



*All dimensions are nominal

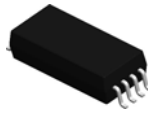
| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|-----|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| AMC1400QDWLRQ1 | SOIC | DWL | 8 | 500 | 330.0 | 24.4 | 18.55 | 7.2 | 4.5 | 24.0 | 24.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS

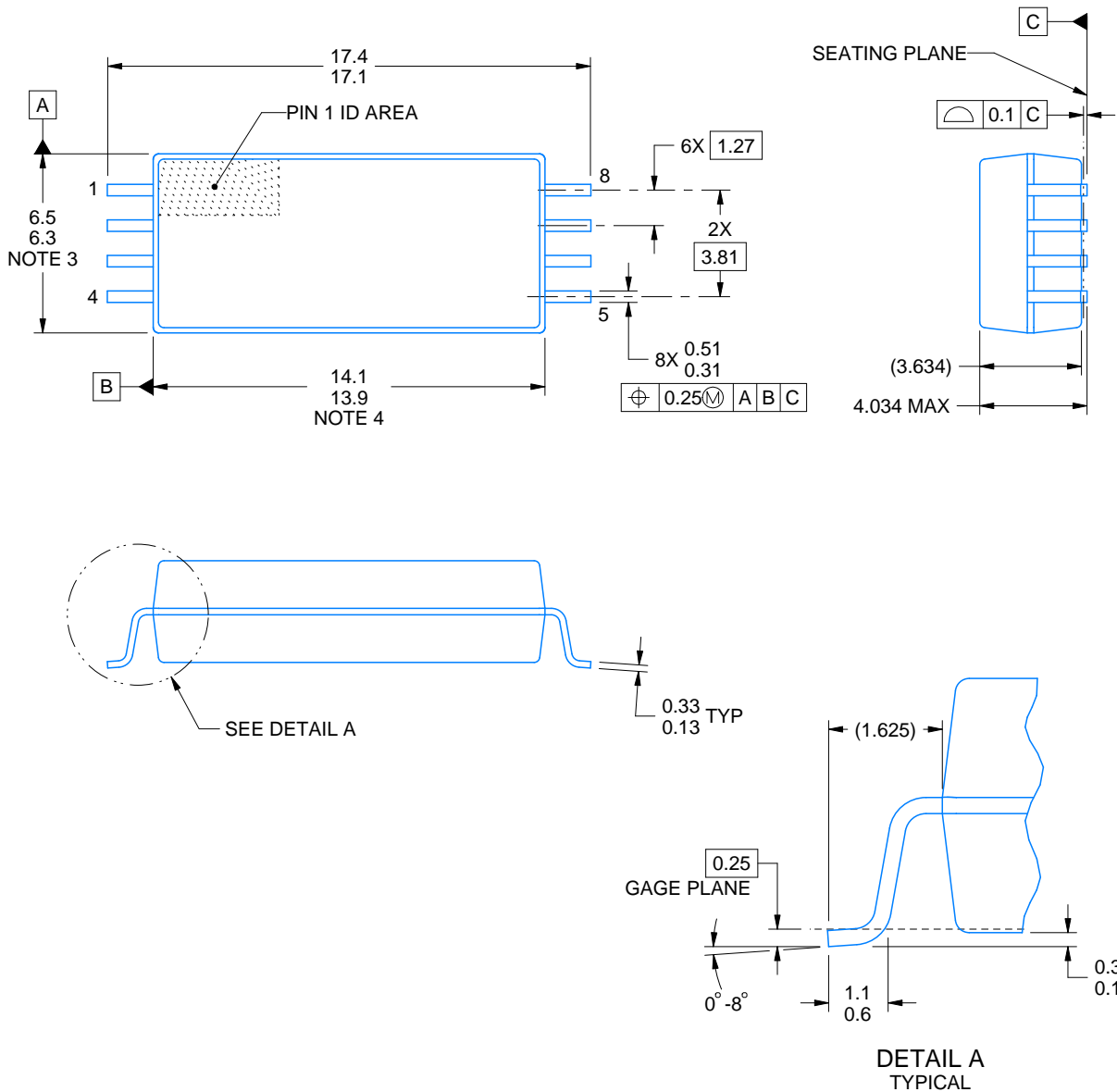


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|-----|-------------|------------|-------------|
| AMC1400QDWLRQ1 | SOIC | DWL | 8 | 500 | 356.0 | 356.0 | 45.0 |

DWL0008A**PACKAGE OUTLINE****SOIC - 4.034 mm max height**

PLASTIC SMALL OUTLINE



4224743/A 01/2019

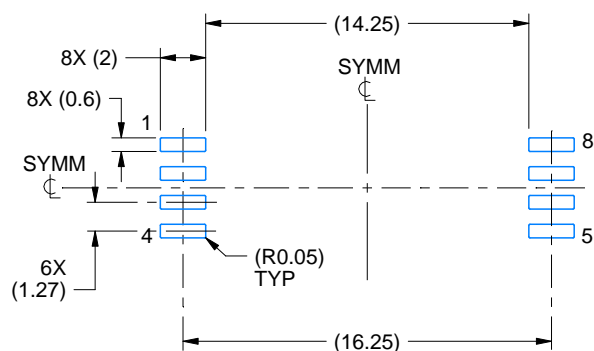
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 mm per side.
4. This dimension does not include interlead flash.

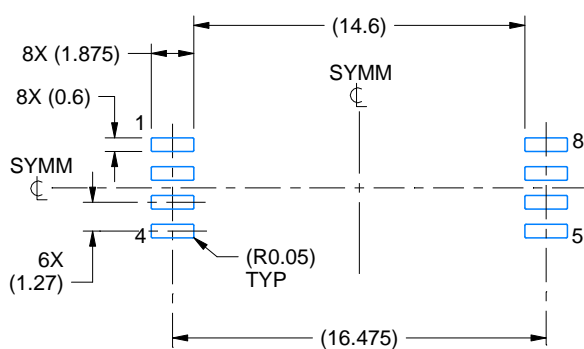
DWL0008A

SOIC - 4.034 mm max height

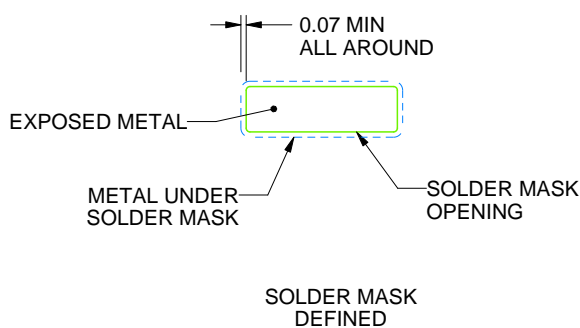
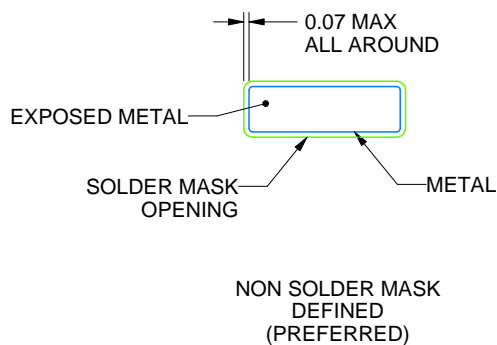
PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
STANDARD
EXPOSED METAL SHOWN
SCALE:3X



LAND PATTERN EXAMPLE
PCB CLEARANCE & CREEPAGE OPTIMIZED
EXPOSED METAL SHOWN
SCALE:3X



SOLDER MASK DETAILS

4224743/A 01/2019

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

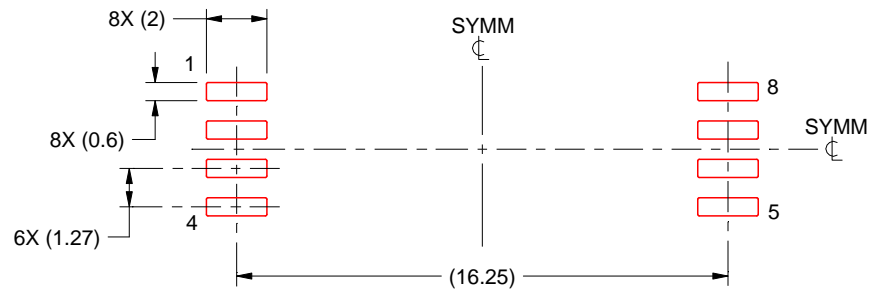
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

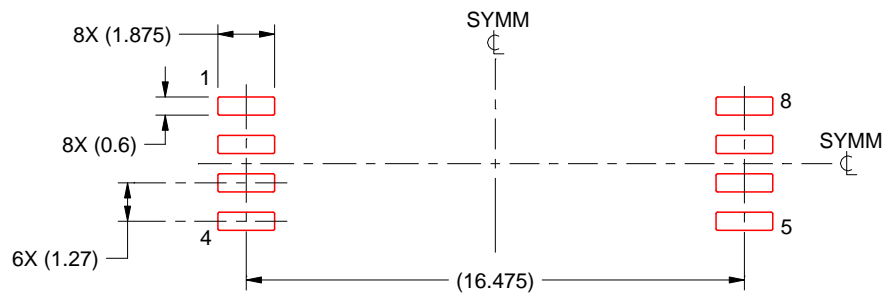
DWL0008A

SOIC - 4.034 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
STANDARD
BASED ON 0.125 mm THICK STENCIL
SCALE:4X



SOLDER PASTE EXAMPLE
PCB CLEARANCE & CREEPAGE OPTIMIZED
BASED ON 0.125 mm THICK STENCIL
SCALE:4X

4224743/A 01/2019

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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